

# UMZ-822-D16-G

### MICROSTRIP VOLTAGE CONTROLLED OSCILLATOR

Package: D16, 12.7mm x 12.7mm x 5.59mm



## Features

- Ultra-Linear Tuning/Low Phase Noise
- Frequency: 4600MHz to 5300MHz
- Resonator: Microstrip
- PCB: Rogers
- Package Size: 12.7mm x 12.7mm x 5.59mm (0.5in x 0.5in x 0.22in)

## Applications

- Frequency Synthesizers
- Up & Down Converters
- Instrumentation
- Wideband Frequency Applications



Functional Block Diagram

## **Product Description**

This series of VCO modules offers ultra-linear tuning across their specified frequency band.

#### **Ordering Information**

UMZ-822-D16-G Contact us at 1-480-756-6070

### Optimum Technology Matching® Applied

🗌 GaAs HBT	SiGe BiCMOS	🗌 GaAs pHEMT
GaAs MESFET	Si BiCMOS	□_Si CMOS
🗌 InGaP HBT	SiGe HBT	🗹 Si BJT

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GaN HEMT BiFET HBT LDMOS

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#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Operating Ambient Temperature[1]	-40 to +85	°C
Storage Temperature	-55 to +125	°C

[1] Frequency drift: 22MHz typical (either extreme)



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

Parameter		Specification		11	Octo dittion
	Min.	Тур.	Max.	Unit	Condition
Overall					
Frequency Range	4600		5300	MHz	
Tuning Voltage	0.2		8	V <sub>DC</sub>	
Tuning Sensitivity		125		MHz/V	
Output Power	-3	0	3	dBm	
	-3			dBm	At V <sub>T</sub> =0
Output Phase Noise		-63	-58	dBc/Hz	1kHz
		-89	-84	dBc/Hz	10kHz
		-109	-104	dBc/Hz	100kHz
		-149	-144	dBc/Hz	1000 kHz
Second Harmonic		-20	-10	dBc	
Frequency Pulling		3	6	MHz p-p	At 12dBr, all phases
Tuning Port Capacitance		10		pF	
Modulation Bandwidth		1000		kHz	3dB BW
Frequency Pushing		3	6	MHz/V	
Power Supply	· · ·				
Operating Voltage		5		V	
Supply Current		27		mA	





## Package Drawing & Pin Outs

12.7mm x 12.7mm x 5.59mm (0.5in x 0.5in x 0.22in)

